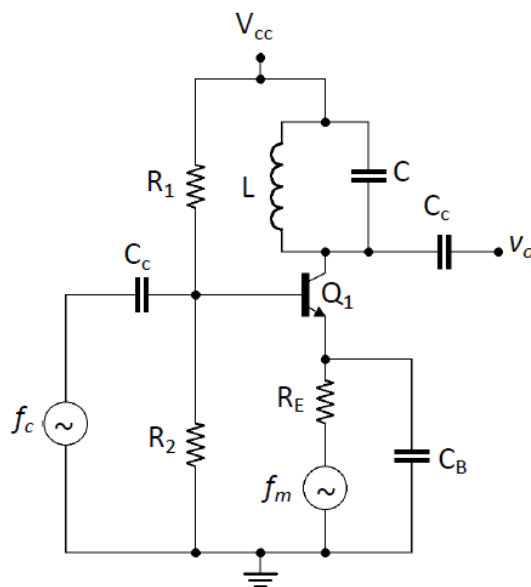
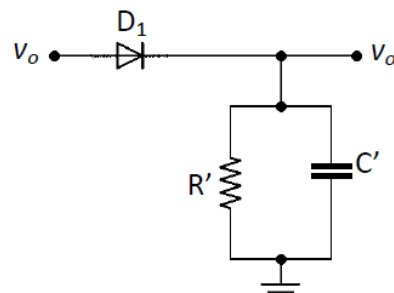


**15ECE381 Circuits and Communication Laboratory****B. Tech (ECE) – V Semester****Experiment 6****Amplitude Modulation and Demodulation****NAME : B SUMANTH****ROLL NO : CB.EN.U4ECE18211****SECTION : ECE-C****GROUP : C2****Aim :**

To design simple circuits to demonstrate the concepts of Amplitude modulation and demodulation.

**Instructions:**

1. All resistors used in your design should be from the E24 series
2. You may make use power supplies of  $\pm 10$  V.

**Fig. 1****Fig. 2****Procedure:**

1. Consider the circuit shown in Fig. 1. Set up the amplifier consisting of the BJT Q1 and the resistors R1 and R2 along with RE and the bypass capacitor CB. Use the SL100 for Q1. The tuned circuit formed by L and C is part of the load impedance for this amplifier. Set  $V_{cc} = 10$  V. The values of the various components are as follows:  $R_1 = 220$  k $\Omega$ ;  $R_2 = 56$  k $\Omega$ ;  $R_E = 1$  k $\Omega$ ;  $L = 100$  mH;  $C = 100$  nF. The emitter-bypass capacitance may be assumed to be as large as 1  $\mu$ F. Please note that all capacitors are of ceramic type. For this part of the experiment,  $f_c$  and  $f_m$ , which are two function generators, need not be connected.
2. Determine the quiescent point of the transistor and note down your readings in Table 1.

**Table 1: operating point of the transistor Q<sub>1</sub>.**

| V <sub>B</sub> | V <sub>C</sub> | V <sub>E</sub> | I <sub>E</sub> |
|----------------|----------------|----------------|----------------|
|                |                |                |                |

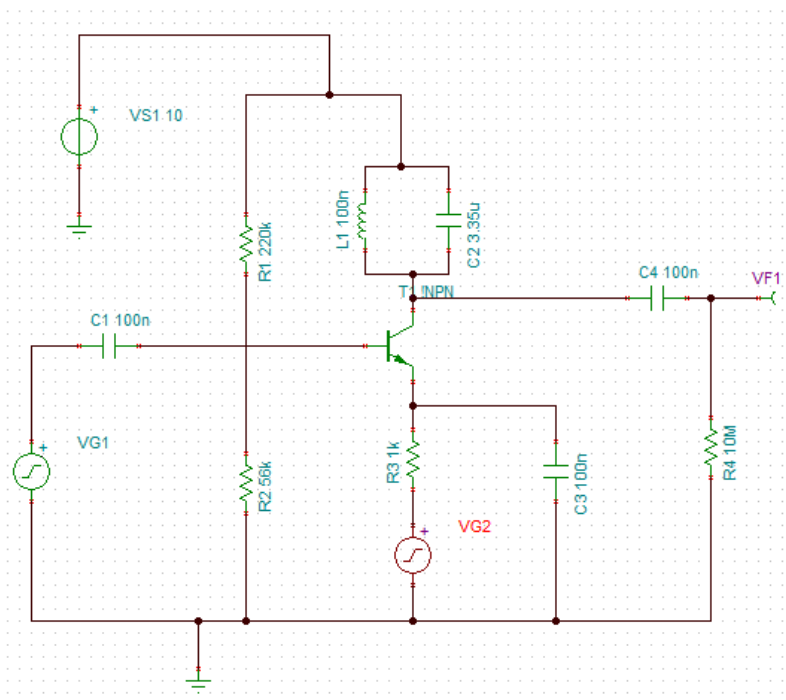
- Now connect up the function generators  $f_c$  and  $f_m$  as shown in Fig. 1, where  $f_c$  stands for the carrier frequency and  $f_m$  represents the modulating frequency.
- For the chosen values of the resistances and capacitances, estimate the required carrier frequency and the function generator  $f_c$  may be set to an amplitude of 5 V and the estimated frequency.
- Similarly,  $f_m$  may be adjusted to provide a signal of amplitude 2 V or less and of frequency 1 kHz.
- The coupling capacitors  $C_c$  may be taken as 1 mF (ceramic).
- Note down the waveform at  $v_o$ . (You might have to adjust  $f_c$  and  $f_m$  to obtain a clean waveform at  $v_o$ ).
- Repeat 6 for different values of the amplitude of  $f_m$ . Calculate the modulation index in each case.

**Demodulation:**

- Connect up the circuit shown in Fig. 2. The diode  $D_1$  can be chosen as OA79 or any high frequency point contact diode.  $R'$  is chosen as 330 k $\Omega$  and  $C'$  as 1 nF.
- Connect the output of your modulator (Fig. 1) to the input of Fig. 2. Plot the waveform obtained at the output  $v_o'$ . How is this different from the modulating signal  $f_m$ ?
- Replace the  $D_1$  with the 1N4007 diode and repeat 9. What do you observe?

**Questions:**

- If the carrier of an amplitude modulation system is given by  $V_c(t) = 5 \sin(\omega t)$ ,  $f = 275$  kHz and the information to be coded is represented as  $V_m(t) = 0.2 \sin(2\pi \cdot 1000t)$ , design a suitable system and demonstrate its operation. Determine the modulation index,  $m$ . Plot  $v_c(t)$ ,  $v_m(t)$  and the output of the AM system.



### Amplitude Modulation

WKT,

$$2\pi f_c = \frac{1}{\sqrt{LC}}$$

Given,  $f_c = 275 \text{ K}$

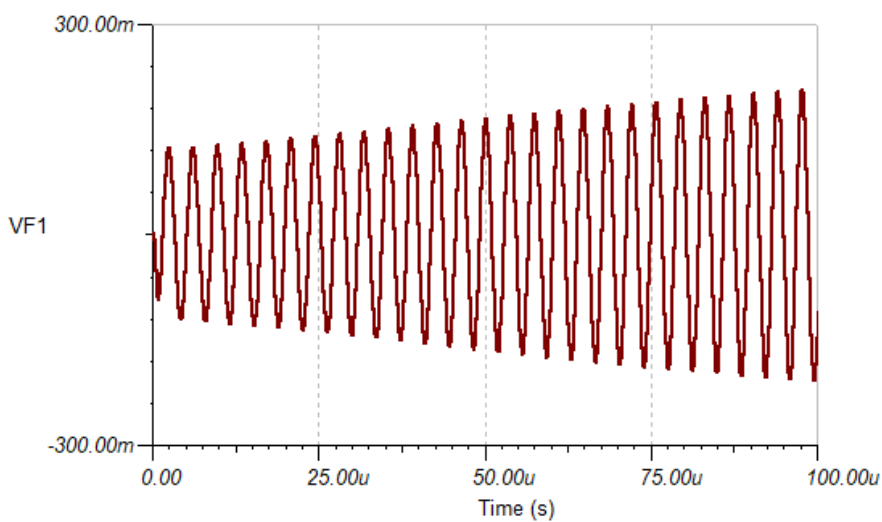
assume  $L = 0.1 \mu\text{H}$

$$\Rightarrow 2\pi (275 \text{ K}) = \frac{1}{\sqrt{(0.1 \mu\text{H})C}} \Rightarrow 0.1 \mu\text{H} C = \left(\frac{1}{2\pi \cdot 275 \text{ K}}\right)^2$$

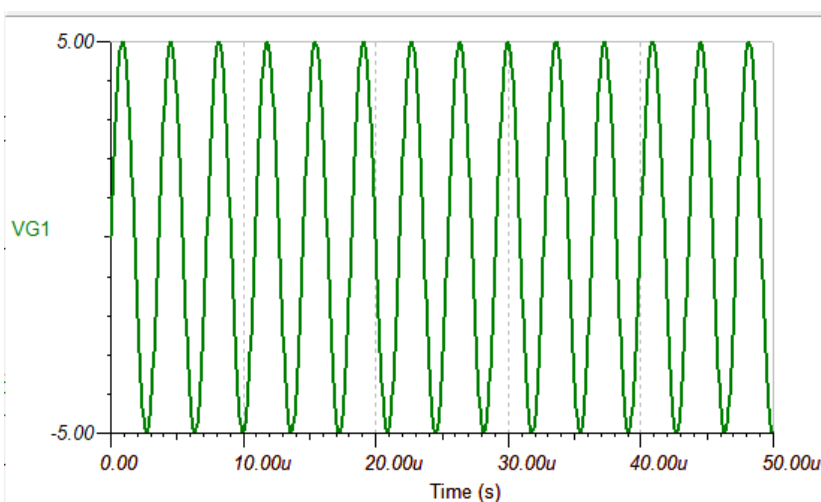
$$0.1 \mu\text{H} C = 3.35 \times 10^{-13}$$

$$\Rightarrow C = 3.35 \mu\text{F}$$

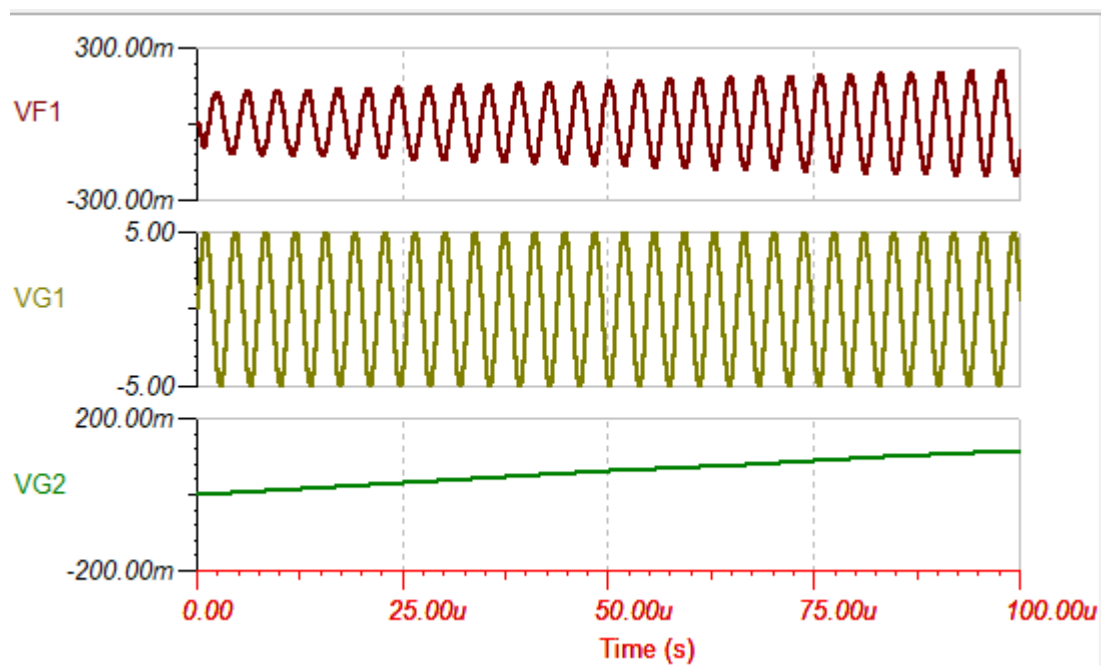
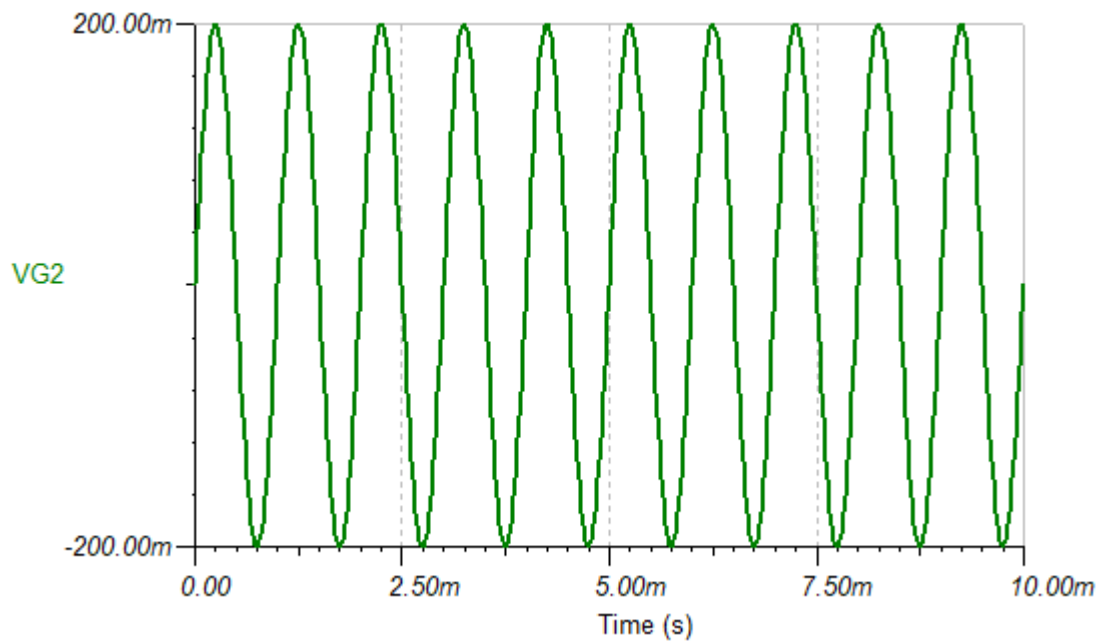
### Amplitude Modulation



### Carrier Signal



## Message Signal



We know that modulation index =  $A_m/A_c$

Given  $A_m = 200\text{mVolts} = 0.2\text{ Volts}$

$A_c = 5\text{ volts}$

So  $\mu = 0.2/5 = 0.04$

So modulation Index is 0.04

**Demodulation:**

Demodulation

WKT,

$$f_0 = \frac{1}{2\pi RC} \quad \text{where } f_0 \text{ is cutting frequency}$$

and

$$f_m \leq f_0 \leq f_c$$

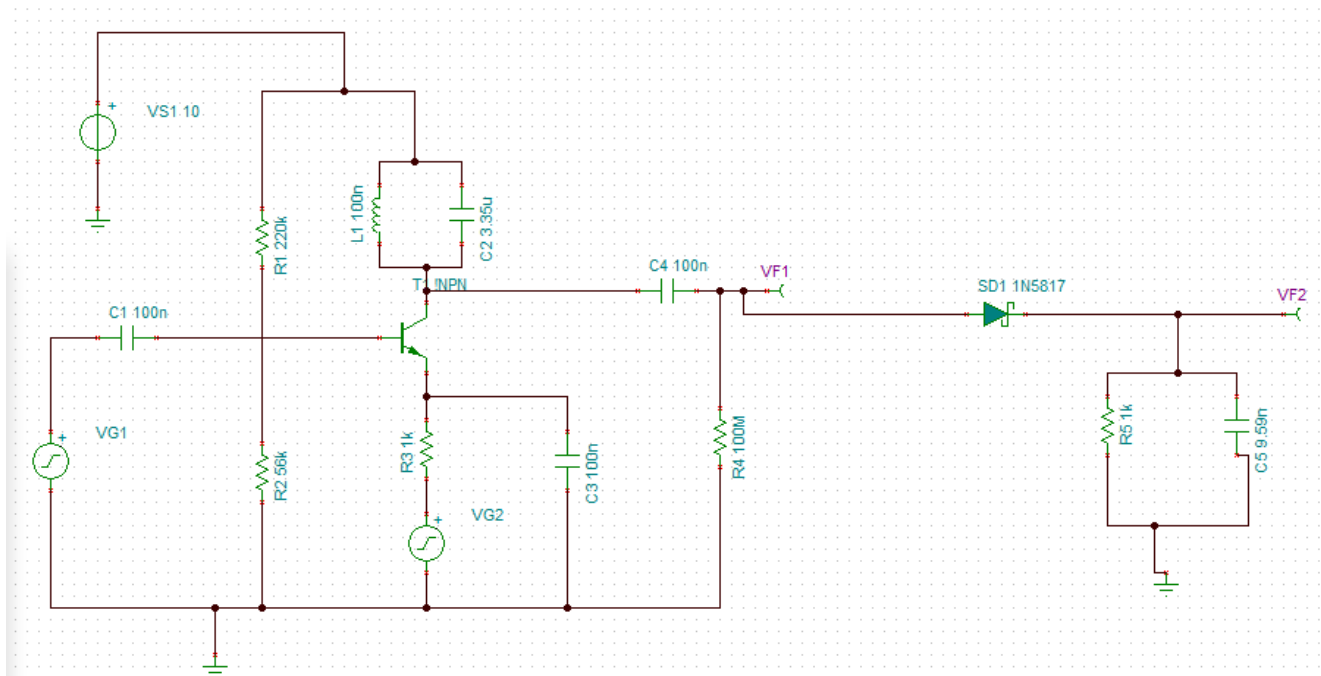
$$f_0 = \sqrt{f_c \times f_m} = \sqrt{820K}$$

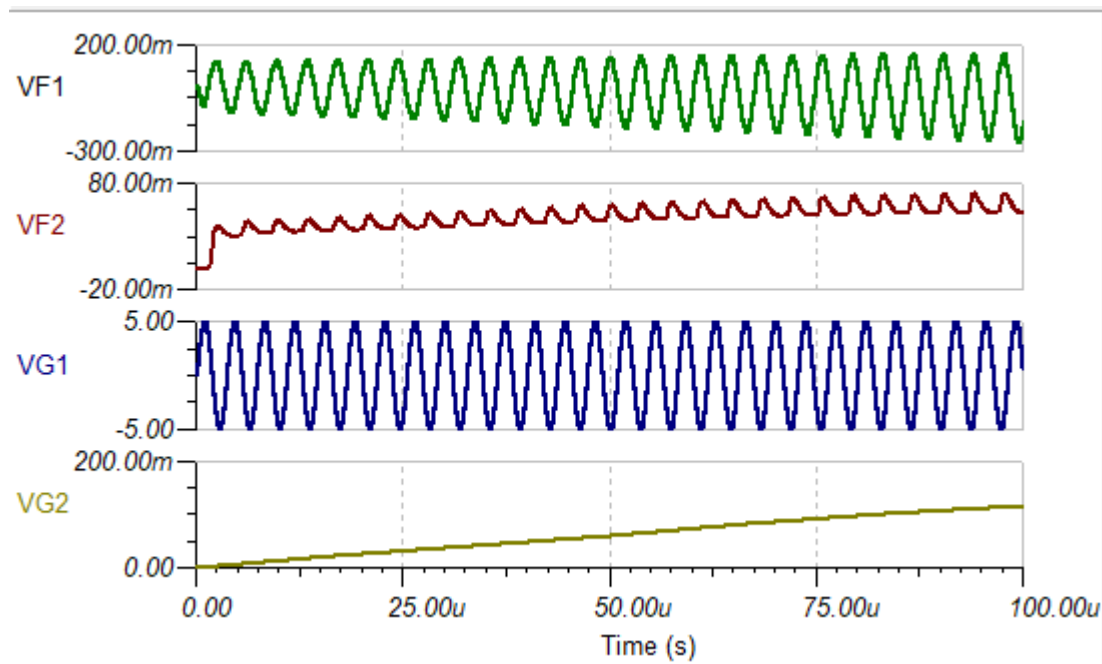
$$f_0 = \sqrt{275K \times K} = \sqrt{275K} = 16583$$

$$\Rightarrow RC = \frac{1}{2\pi f_0} = \frac{6.03 \times 10^{-5}}{2\pi} = \frac{603 \mu}{2\pi} = 9.59 \mu$$

assume

$$\Rightarrow \boxed{R=1K}, \quad \boxed{C=9.59nF}$$

**Circuit:**



### Inference Questions:

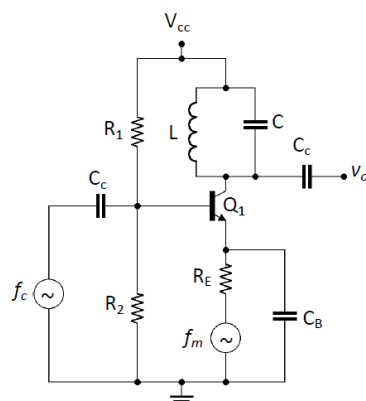


Fig. 1

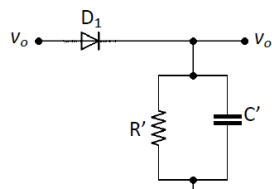


Fig. 2

1. What is the purpose of the tuned LC circuit ? What is its frequency ?

**Ans:** The purpose of LC circuit is to generate a signal at particular frequency or picking out a signal at particular frequency. And it is also used so that the amplitude of the carrier signal changes instantly according to the message signal.

2. Try for  $\mu = 1$  and  $\mu > 1$ . Give the design and corresponding outputs.

**ANS:** The  $\mu = 1$  is the situation where under modulation takes place .So. the message signal will be 100% modulated. For  $\mu > 1$  , over modulation occurs. The signal will be clipped as the envelope detector cannot detect the whole signal. It is when message has more amplitude than carrier.

3. Did you notice any over-modulation in any case?

**ANS:** No I didn't notice any over modulation for given frequencies..

4 What is the purpose of the combination of  $R'$  and  $C'$  at the output of the demodulator ? How does it affect the operation of the demodulator ?

**ANS:** A capacitor is connected across resistor , effectively filtering out the carrier and thus recovering the original modulating signal.

5 What will be the difference in performance when we use 1N4007 and OA79/high frequency diodes.

**ANS:** The only difference is the maximum repetitive capability which is maximum for 1N4007 compared to OA79.